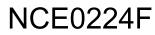


(2) D



# NCE N-Channel Enhancement Mode Power MOSFET

#### Description

The NCE0224F uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

- $V_{DS} = 200V, I_D = 24A$  $R_{DS(ON)} < 80m\Omega @ V_{GS} = 10V$  (Typ:64m $\Omega$ )
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

#### Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

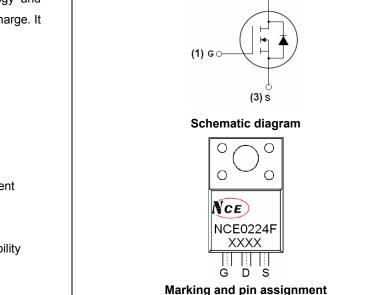
100% ΔVds TESTED!

#### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0224F	NCE0224F	TO-220F	-	-	-

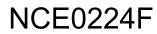
#### Absolute Maximum Ratings (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	200	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	Ι <sub>D</sub>	24	А
Drain Current-Continuous(T <sub>C</sub> =100℃)	I <sub>D</sub> (100℃)	16.5	А
Pulsed Drain Current	I <sub>DM</sub>	72	A
Maximum Power Dissipation	PD	45	W
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	250	mJ
Operating Junction and Storage Temperature Range	$T_{J},T_{STG}$	-55 To 175	°C









#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient <sup>(Note 2)</sup>	R <sub>eja</sub>	3.33	°C/W
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#### Electrical Characteristics (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Мах	Unit
Off Characteristics	·	·				
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	200	220	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =200V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)	·	·				
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	2	3	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =15A	-	64	80	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =50V,I <sub>D</sub> =11A	25	-	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	C <sub>lss</sub>			4200		PF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =25V,V <sub>GS</sub> =0V,		163		PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz		75		PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t <sub>d(on)</sub>		-	10	-	nS
Turn-on Rise Time	tr	V <sub>DD</sub> =100V,I <sub>D</sub> =15A	-	18	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{GEN}$ =2.5 $\Omega$	-	22	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	5	-	nS
Total Gate Charge	Qg	V/ 400V/1 45A		60		nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =100V,I <sub>D</sub> =15A,		19		nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V		17		nC
Drain-Source Diode Characteristics			ł			•
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =11A	-	-	1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>	-	-	-	24	A
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF = 15A	-	90	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs(Note3)	-	300	-	nC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

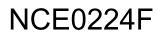
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition:Tj=25 $^{\circ}$ C,V<sub>DD</sub>=100V,V<sub>G</sub>=10V,L=0.5mH,Rg=25 $\Omega$

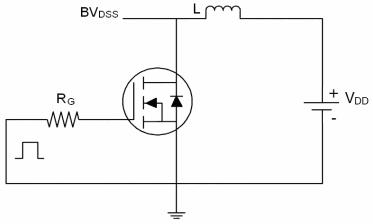


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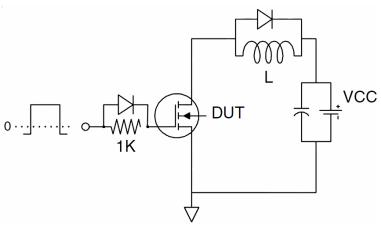




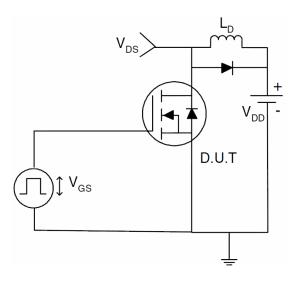
## Test Circuit 1) E<sub>AS</sub> Test Circuits



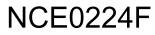
### 2) Gate Charge Test Circuit



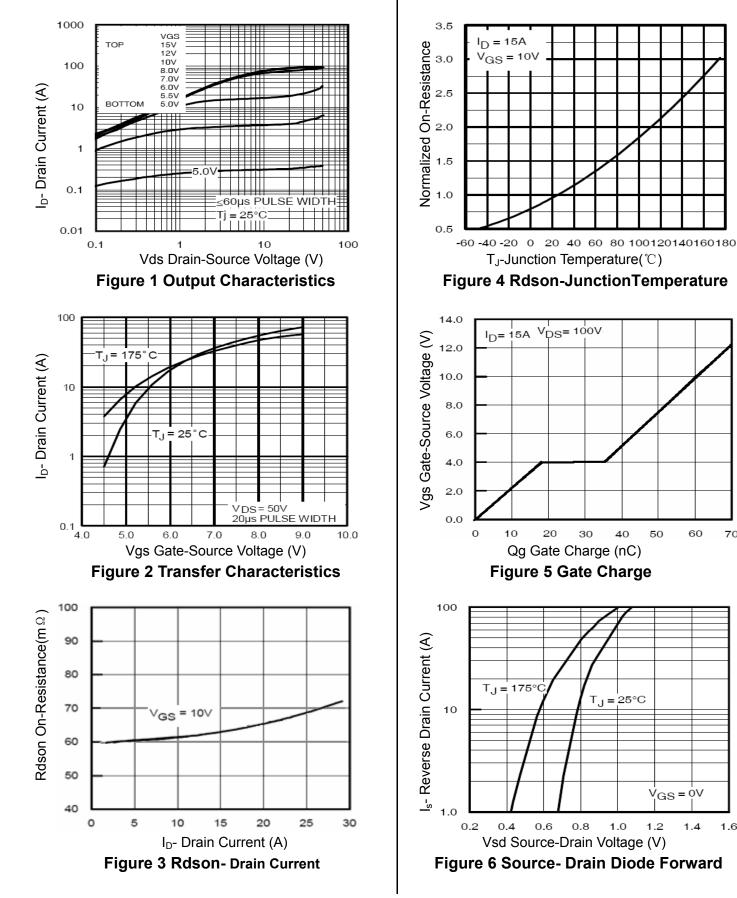
3) Switch Time Test Circuit







## **Typical Electrical and Thermal Characteristics (Curves)**



1.6

70

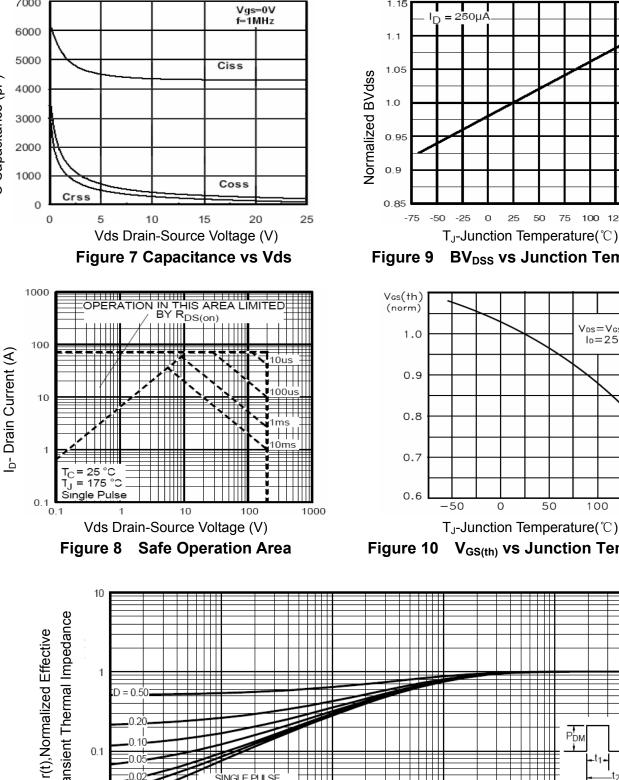


7000

C Capacitance (pF)

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1.15



**Pb Free Product** 

**NCE0224F** 

100 125 150 175

**BV**<sub>DSS</sub> vs Junction Temperature

75

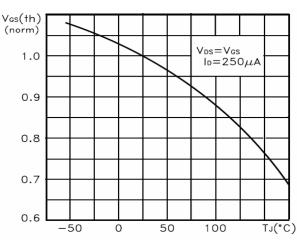


Figure 10 V<sub>GS(th)</sub> vs Junction Temperature

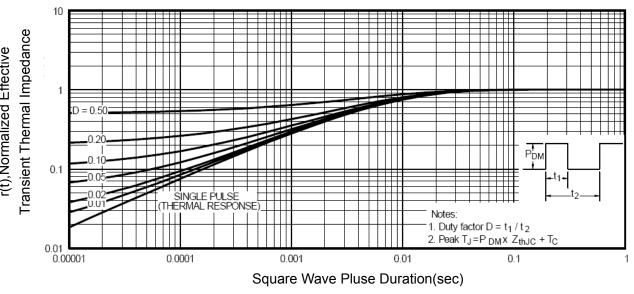


Figure 11 Normalized Maximum Transient Thermal Impedance

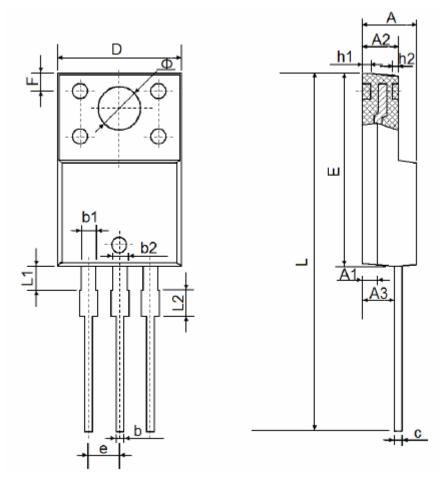


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# NCE0224F

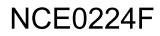
## **TO-220F Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min.	Max.	Min.	Max.		
A	4.300	4.700	0.169	0.185		
A1	1.30	DREF	0.051REF			
A2	2.800	3.200	0.110	0.126		
A3	2.500	2.900	0.098	0.114		
b	0.500	0.750	0.020	0.030		
b1	1.100	1.350	0.043	0.053		
b2	1.500	1.750	0.059	0.069		
с	0.500	0.750	0.020	0.030		
D	9.960	10.360	0.392	0.408		
E	14.800	15.200	0.583	0.598		
e	2.540	)TYP.	0.100TYP			
F	2.70	2.700REF		0.106REF		
Φ	3.500REF		0.138REF			
h1	0.80	DREF	0.031REF			
h2	0.500	DREF	0.020REF			
L	28.000	28.400	1.102	1.118		
L1	1.700	1.900	0.067	0.075		
L2	1.900	2.100	0.075	0.083		







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